

JC17 Rec'd PCT/PTO Sheet 1 of 1 14 JUN 2005

Form PTO-1449 (REV. 8-83) US Dept. of Commerce PATENT & TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)			ATTY DOCKET NO. 124231	APPLICATION NO. New U.S. National Stage of PCT/JP03/016794 10 / 538878		
			APPLICANTS Masahiro SAKURADA et al.			
			FILING DATE June 14, 2005	GROUP <i>1708</i>		
U.S. PATENT DOCUMENTS						
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS
FOREIGN PATENT DOCUMENTS						
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS
<i>FH</i>	1	JP A 2000-351690 w/ abst & transl	12/19/2000	JAPAN	—	—
<i>FH</i>	2	JP A 2000-178099 w/ abst & transl	6/27/2000	JAPAN	—	—
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)						
<i>FH</i>	3	VORONIKOV, "The Mechanism of Swirl Defects Formation in Silicon," <i>Journal of Crystal Growth</i> , vol. 59, no. 3, pp. 625-643 {March 1, 1982}				
<i>FH</i>	4	DUPRET et al., "Global Modelling of Heat Transfer in Crystal Growth Furnaces," <i>Int. J. Heat Mass Transfer.</i> , vol. 33, no. 9, pp. 1849-1871 {April 7, 1998}				
EXAMINER <i>J. H. Johnson</i>					DATE CONSIDERED <i>6/27/2005</i>	
Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.						

Date: June 14, 2005